Temperature dependence of piezoelectric properties of high- $T_C$ Bi $(\text{Mg}/2\text{Ti}/2)$ O 3 – PbTiO 3

Jun Chen, Xiaoli Tan, Wook Jo, and Jürgen Rödel

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Temperature dependence of piezoelectric properties of high-$T_C$ Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–PbTiO$_3$

Jun Chen,1,a Xiaoli Tan,2 Wook Jo,1 and Jürgen Rödel1
1Institute of Materials Science, Technische Universität Darmstadt, Petersenstr. 23, 64287 Darmstadt, Germany
2Department of Materials Science and Engineering, Iowa State University, Ames, Iowa 50011, USA

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The temperature dependence of both polarization and electric-field induced strain was investigated for (1−$x$)Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–$x$PbTiO$_3$ ($x$=0.36, 0.37, and 0.38), with the morphotropic phase boundary located at $x$=0.37. Remanent polarization ($P_r$) and maximum polarization ($P_{max}$) of all compositions are enhanced with increasing temperature up to 175 °C, which is rationalized as improved domain switching due to reduced tetragonality ($c/a$). The hysteresis during unipolar electric cycling tends to decrease with increase in the fraction of tetragonal phase. Temperature dependent x-ray diffraction demonstrates that switched non-180° domains are stable against thermal depoling above 200 °C, which indicates that the currently investigated materials are suitable for high temperature applications. This promising high-$T_C$ piezoelectric is further discussed with reference to oxygen octahedron of the tilted R3c and untitled R3m space groups and the tolerance factor ($t$). © 2009 American Institute of Physics. [DOI: 10.1063/1.3191666]

I. INTRODUCTION

Over the past decade, a great demand has been placed for piezoelectric materials for usage at temperatures as high as possible, especially in the aerospace and automotive industries.1–5 The operating temperature of piezoelectric ceramics is generally limited to one-half of the Curie point ($T_C$) due to loss of polarization, typically at temperatures lower than 200 °C [e.g., 150 °C for the conventional piezoelectric materials based on the Pb(Zr$_{1−x}$Ti$_x$)O$_3$ (PZT)] with a Curie temperature, $T_C$=386 °C.4 After excellent piezoelectric properties for (1−$x$)BiScO$_3$–$x$PbTiO$_3$ (BS-PT) near the morphotropic phase boundary (MPB) ($x$=0.64) were reported (piezoelectric coefficient, $d_3$=460 pC/N, planar coupling coefficient, $k_p$=0.56, and $T_C$=450 °C) recently,5,6 the discovery of several promising high temperature piezoelectric materials with high performance followed in the general BiMeO$_3$–PbTiO$_3$ system,5,24 where Me can be a single cation of valency +3 (e.g., Sc$_{3+}$ and Fe$_{3+}$) or a mixture of cations with an average valence of +3 (e.g., Mg$_{1/2}$Ti$_{1/2}$ and Ni$_{2/3}$Nb$_{1/3}$). It has been proposed that the Bi substitution plays an unusual role of considerable enhancement of both Curie temperature ($T_C$) and tetragonality ($c/a$), which results from a strong coupling between Pb/Me cations and B-site cations of strong ferroelectric activity, such as Ti, Zn, and Fe.25 Although BS-PT shows good piezoelectric properties even superior to the conventional PZT-based piezoceramics, its market application is highly restricted by the high price of Sc$_2$O$_3$. Hence, most recent studies have been focusing on nonscandium perovskites.12–24 In fact, possible new compositions in BiMeO$_3$–PbTiO$_3$-based systems are plenty, because B-site Me of BiMeO$_3$ could be any combination, which gives an average valence of +3. According to the currently available literature, however, the design of BiMeO$_3$–PbTiO$_3$ piezoceramics faces a significant challenge in that only few systems form a MPB with PbTiO$_3$. Most BiMeO$_3$ compounds show limited solubility in PbTiO$_3$ such that the MPB is rarely reached. This has been demonstrated in such systems as Bi(Zn$_{2/3}$Ti$_{1/3}$)O$_3$–PbTiO$_3$ (BZT-PT) and Bi(Zn$_{2/3}$Nb$_{1/3}$)O$_3$–PbTiO$_3$.20–24 Table I lists the piezoelectric and related properties of BiMeO$_3$–PbTiO$_3$ piezoceramics available in literature. It should be noted that most BiMeO$_3$–PbTiO$_3$ compositions have a relatively high $T_C$. However, except BS-PT,5 Bi(Ni$_{1/2}$Ti$_{1/2}$)O$_3$–PbTiO$_3$ (Ref. 12) and Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–PbTiO$_3$,13 all known BiMeO$_3$–PbTiO$_3$-based systems have low or inferior piezoelectric properties at their MPB. As Bi(Ni$_{1/2}$Ti$_{1/2}$)O$_3$–PbTiO$_3$ suffers from high conductivity and dielectric losses,12 we chose Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–PbTiO$_3$ for our current study.

For consideration as high-$T_C$ piezoelectric, the temperature dependence of piezoelectric properties is most crucial for applications such as actuators and sensors. However, most studies so far have been related only to structure, ferroelectric, and piezoelectric properties at room temperature, with few exceptions.14,26 In this study, therefore, ceramics of (1−$x$)Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–$x$PbTiO$_3$ near the MPB ($x$=0.36, 0.37, and 0.38) were prepared by the conventional solid-state reaction method to investigate the temperature dependence of polarization and strain of bipolar and unipolar electric loading. These are then correlated with the crystal structures as determined by high temperature x-ray diffraction (XRD).

II. EXPERIMENT

(1−$x$)Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$–$x$PbTiO$_3$ (abbreviated as BMT-PT100) ceramics of three compositions ($x$=0.36, 0.37, and 0.38) were prepared by the conventional solid-state reaction method. MgTiO$_3$ was first synthesized as a precur-

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1Author to whom correspondence should be addressed. Electronic mail: junchen@metall.ustb.edu.cn.
sor at 1400 °C for 4 h using reagent graded oxide precursors and then mixed with PbO (99.9%, Alfa Aesar), TiO₂ (99.9%, Alfa Aesar), and Bi₂O₃ (99.975%, Alfa Aesar) according to the stoichiometric formulas of each composition. These powder mixtures were ball milled in ethanol for 12 h. Calcination at 850 °C for 5 h was then followed by renewed ball milling for another 12 h. Calcined powders were uniaxially pressed into pellets with a diameter of 10 mm and thickness of ~1 mm, and then hydrostatically compacted at 200 MPa. The green compacts were embedded in a covered crucible at 1100 °C for 2 h.

XRD (STOE STADI P) at room temperature was performed to reveal the crystal structures. The temperature dependence of the crystal structure of poled pellets of BMT-PT38 was further studied from room temperature to 325 °C (Bruker Siemens D8). The data were collected in 2θ angular range of 20°–60° using a step (0.02°) scanning mode with step duration of 5 s. The diffraction patterns were calculated with the software FULLPROF. For electrical measurements, sintered pellets were ground and polished to a thickness of ~0.5 mm. The polished samples were electroded with silver paste and then fired at 550 °C for 30 min. A triangular waveform at a frequency of 1 Hz was applied to monitor the temperature dependence of polarization (P) and field-induced longitudinal strain (S) curves in a silicone oil bath by using a Sawyer–Tower circuit equipped with a strain gauge. The measurement was performed from room temperature to 175 °C with an interval of 25 °C. Before collecting data for each temperature, the sample was held at each specified temperature for 30 min to minimize thermal fluctuation. For the temperature dependent XRD and the measurement of the small-signal piezoelectric coefficient d₃₃, samples were poled at 120 °C under an electric field of 5 kV/mm for a dwell time of 10 min, and cooled down to room temperature under the applied electric field. After 24 h aging of the poled sample, the d₃₃ value was measured using a Berlincourt meter (YE 2730, Sinocera, Shanghai, China).

### III. RESULTS AND DISCUSSION

(1−x)Bi(Mgₓ/2Ti₁/2)O₃−xPbTiO₃ forms a solid solution in a wide range of compositions, with 0.3 ≤ x ≤ 1.0. The solubility limit of BMT (70 mol %) is considerably higher than the other types of (1−x)BiMeO₃−xPbTiO₃, e.g., 40 mol % of BS for BSPT,⁵ and 35 mol % of BZT for BZT-PT.²² The room temperature XRD patterns of (1−x)Bi(Mgₓ/2Ti₁/2)O₃−xPbTiO₃ near the MPB (x = 0.36, 0.37, and 0.38) are shown in Fig. 1(a). These are consistent with a perovskite structure for all three compositions without any trace of secondary phases. BMT-PT38 is indexed as tetragonal with the apparent splitting between (002) and (200) diffraction peaks, while BMT-PT36 is predominantly rhombohedral with a small amount of tetragonal phase. Both rhombohedral and tetragonal symmetries are present in BMT-PT37.¹³ From a structural point of view, therefore, the MPB that consists of tetragonal (T, space group: P4mm) and rhombohedral (R, space group: R3c) phases is determined to

### TABLE I. Piezoelectric and related properties of (1−x)BiMeO₃−xPbTiO₃ in the composition near the MPB. The ceramics are sorted by the value of d₃₃ in descending order.

<table>
<thead>
<tr>
<th>Compound</th>
<th>MPB (mol % PT)</th>
<th>Tₑ (°C)</th>
<th>d₃₃ (pC/N)</th>
<th>kₑ</th>
<th>tan δ</th>
<th>Eₑ (kV/mm)</th>
<th>c/a</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.36BiScO₃−0.64PbTiO₃</td>
<td>64</td>
<td>450</td>
<td>460</td>
<td>0.56</td>
<td>0.027</td>
<td>2.0</td>
<td>1.023</td>
<td>5</td>
</tr>
<tr>
<td>0.45Bi(Sr₀.₇Ca₀.₃)O₃−0.55PbTiO₃</td>
<td>55</td>
<td>440</td>
<td>298</td>
<td>0.49</td>
<td>0.033</td>
<td>2.2</td>
<td>1.021</td>
<td>9</td>
</tr>
<tr>
<td>0.51Bi(Niₓ/₂T₂i/₂)O₃−0.49PbTiO₃</td>
<td>49</td>
<td>400</td>
<td>260</td>
<td>...</td>
<td>...</td>
<td>3.8</td>
<td>1.018</td>
<td>12</td>
</tr>
<tr>
<td>0.63Bi(Mgₓ/₂T₁i/₂)O₃−0.37PbTiO₃</td>
<td>37</td>
<td>478</td>
<td>225</td>
<td>...</td>
<td>0.063</td>
<td>5.0</td>
<td>1.034</td>
<td>13 and 15</td>
</tr>
<tr>
<td>0.60(Biₓ/₂La₀.₃)O₃−0.40(Pbₓ/₂Ba₀.₆)O₃</td>
<td>40</td>
<td>386</td>
<td>186</td>
<td>0.37</td>
<td>0.04</td>
<td>2.8</td>
<td>1.030</td>
<td>16</td>
</tr>
<tr>
<td>0.38Bi(Mgₓ/₂W₁/₂)O₃−0.62PbTiO₃</td>
<td>62</td>
<td>220</td>
<td>150</td>
<td>...</td>
<td>0.046</td>
<td>4.2</td>
<td>1.002</td>
<td>17 and 18</td>
</tr>
<tr>
<td>0.35Bi(Niₓ/₂Nb₁/₂)O₃−0.65PbTiO₃</td>
<td>67</td>
<td>273</td>
<td>140</td>
<td>0.22</td>
<td>0.11</td>
<td>2.8</td>
<td>19</td>
<td></td>
</tr>
<tr>
<td>0.4Bi(Scₓ/₂Ga₁/₂)O₃−0.6PbTiO₃</td>
<td>60</td>
<td>477</td>
<td>124</td>
<td>...</td>
<td>0.05</td>
<td>3.9</td>
<td>1.027</td>
<td>10</td>
</tr>
<tr>
<td>0.33(Biₓ/₂La₀.₃)O₃−0.67PbTiO₃</td>
<td>300</td>
<td>94</td>
<td>...</td>
<td>...</td>
<td>4.7</td>
<td>1.030</td>
<td>20</td>
<td></td>
</tr>
<tr>
<td>0.60BiInO₃−0.85PbTiO₃ (1.5 mol % Nb₂O₃)</td>
<td>542</td>
<td>60</td>
<td>0.11</td>
<td>0.014</td>
<td>12.5</td>
<td>1.067</td>
<td>21</td>
<td></td>
</tr>
</tbody>
</table>

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Fig. 1. (Color online) (a) XRD patterns of (1−x)Bi(Mgₓ/₂Ti₁/₂)O₃−xPbTiO₃ (x = 0.36, 0.37, and 0.38) at room temperature. (b) XRD patterns of the powder and a poled ceramic pellet of 0.62Bi(Mgₓ/₂T₁i/₂)O₃−0.38PbTiO₃.
be in the range of $x=0.36–0.37$. The lattice parameters of tetragonal BMT-PT38 were obtained as $a (b)=3.947(9)$ Å and $c =4.081(1)$ Å, yielding a tetragonality $(c/a=1.034)$ at the tetragonal side of the MPB, which is among the largest in $(1-x)$BiMeO$_3$–xPbTiO$_3$ materials (see Table I). Figure 1(b) depicts the room temperature XRD patterns of tetragonal BMT-PT38 recorded from powders and a poled pellet. A poling-induced texture can be clearly seen from the intensity change in (002) and (200) peaks at around $2\theta=45^\circ$, corresponding to the spontaneous polarization directions of the tetragonal ferroelectric phase.

The temperature dependence of the crystal structure and the thermal stability of polarization were assessed by high temperature XRD on a poled pellet after removal of the silver electrodes. Figure 2 exemplarily shows high temperature XRD patterns from BMT-PT38 in the temperature range of RT to 325 °C with an interval of 50 °C. In the temperature range of RT to 275 °C, BMT-PT38 mainly preserves its tetragonal structure. It is interesting to note that there is no noticeable change in the ratio between the intensities of (002) and (200), which indicates that the switched domains have a good thermal stability in the investigated temperature range essential for a promising candidate for high temperature piezoelectric applications. However, when temperature was further increased to 325 °C, several new diffraction peaks that can be indexed as a pseudocubic phase appear, indicating that a phase transition takes place at around this temperature. An additional peak was also observed at 300–400 °C in the temperature dependence of dielectric constant measurement. The nature of this phase transition at this temperature is not yet understood and subject to further investigations.

The lattice constants of the tetragonal phase are presented in Fig. 3. With increasing temperature, the $a$ (b) axis increases while the $c$ axis decreases, resulting in a reduced $c/a$. A reduced $c/a$ ratio translates into a reduced internal stress level, which is expected to alleviate further domain switching.

The temperature dependence of $P(E)$ and $S(E)$ from room temperature to 175 °C for $(1-x)$Bi$_{0.62}$Mg$_{1.25}$Ti$_{1.25}$O$_3$–xPbTiO$_3$ ($x=0.36, 0.37,$ and 0.38) is depicted in Figs. 4–6. The $P(E)$ and $S(E)$ curves of all three compositions display an archetypal shape for normal ferroelectrics such as PZT. The important ferroelectric properties at room temperature are close to those reported in literature and are summarized in Table II. When compared with the other typical systems listed in Table I, $E_C$ of BMT-PT is comparatively high, which could be attributed to its large tetragonality $(c/a)$ and hence large internal stress level. This is consistent with a decrease in $E_C$ as the amount of tetragonal phase is replaced by rhombohedral phase (see Table II). The lattice distortion of the tetragonal phase, given by $\delta t=(c/a−1)$ with 3.4% for BMT-PT38, is larger in this system than that of the rhombohedral phase, given by $\delta r=(9/8)(d_{111}/d_{111}−1)$ with 0.45% for BMT-PT36. The different behavior between $\delta t$ and $\delta r$ holds also true in other ferroelectric systems, representatively in PZT.

As shown in Figs. 4–6, the coercive field ($E_C$) is decreased as the temperature increases, but $P_{max}$ (polarization at maximum field) and $P_r$ (remanent polarization) were observed to increase with temperature. Temperature dependent polarization and strain are similar between the three compositions. All are enhanced with temperature within the investigated temperature range. At 175 °C, polarization is slightly effected by an increased conductivity. Note that the influence of temperature on polarization is quite different to that of normal ferroelectric materials. Commonly, polarization values decrease continuously up to the Curie temperature ($T_C$). This unusual behavior is rationalized by the fact that the poling field of 8 kV/mm does not suffice to fully pole BMT-PT near room temperature possibly due to severe domain wall locking from its high $c/a$ ratio. The enhanced polarization values at increased temperature are thus ascribed to an increase in the amount of switchable non-180° domains, caused by a reduced $E_C$.

The increase in the total strain with temperature can be explained in a similar manner. For ferroelectric materials, the total strain is provided by a combination of intrinsic piezoelectric effect (lattice straining) and extrinsic piezoelectric effect (domain switching). The intrinsic piezoelectric effect is not expected to increase with decreasing $c/a$ ratio stemming from the increase in temperature (Fig. 3). Hence, the enhancement of electric-field induced strain and polarization is attributed to enhanced domain switching. This is also evident from the changes in the negative strain, which is defined as the difference between the strain at zero electric field and the minimum strain during bipolar cycles. Note that the
negative strain becomes even larger with a reduced $c/a$, and the strain minimum occurs at a lower electric field as the temperature increases. Note that in bulk PZT, both total strain and negative strain decrease with rising temperature, following the reduced lattice distortion.

If application as an actuator for high temperature is contemplated for BMT-PT piezoceramics, then the electric-field induced unipolar strain is an essential parameter. There is a clear distinction between the compositions containing dominantly rhombohedral and tetragonal crystal structures. The strain of BMT-PT increases almost in linear fashion, while the $S(E)$ unipolar curve of BMT-PT bends upward. Strain hysteresis can be quantified as a ratio of the difference between up-poling and down-poling strains at a half maximum electric field to the total strain at the maximum field.

At room temperature, for example, the hysteresis of BMT-PT at 7 kV/mm is almost two times larger than that of BMT-PT (24%). This supports the previous assumption that the high lattice distortion is responsible for the limited contribution from domain switching.

FIG. 4. (Color online) Temperature dependence of (a) $P(E)$ loops, (b) bipolar $S(E)$ curves, (c) $E_c$, and (d) polarization for 0.64Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$ –0.36PbTiO$_3$.

FIG. 5. (Color online) Temperature dependence of (a) $P(E)$ loops, (b) bipolar $S(E)$ curves, (c) $E_c$, and (d) polarization for 0.63Bi(Mg$_{1/2}$Ti$_{1/2}$)O$_3$ –0.37PbTiO$_3$.
since the lattice distortion is smaller in the rhombohedral phase in BMT-PT. A reduced lattice distortion then prompts increased levels of domain switching and increased hysteresis. Figure 7 provides the large-signal $d_{33}$ as a figure of merit for actuator applications. $S_{\text{max}}/E_{\text{max}}$ for all three compositions shows a linear increase with temperature. Large and small signal $d_{33}$ values at room temperature are presented in Fig. 8. The large signal $d_{33}$ is about 20%–40% larger than the small signal one, which can be compared

<table>
<thead>
<tr>
<th>Composition ($x$)</th>
<th>$E_C$ (kV/mm)</th>
<th>$P_{\text{max}}$ ($\mu$C/cm$^2$)</th>
<th>$P_r$ ($\mu$C/cm$^2$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.64Bi(Mg$<em>{1/2}$Ti$</em>{1/2}$)O$_3$–0.36PbTiO$_3$</td>
<td>4.7</td>
<td>44.1</td>
<td>33.2</td>
</tr>
<tr>
<td>0.63Bi(Mg$<em>{1/2}$Ti$</em>{1/2}$)O$_3$–0.37PbTiO$_3$</td>
<td>5.0</td>
<td>42.5</td>
<td>32.4</td>
</tr>
<tr>
<td>0.62Bi(Mg$<em>{1/2}$Ti$</em>{1/2}$)O$_3$–0.38PbTiO$_3$</td>
<td>5.3</td>
<td>39.7</td>
<td>30.2</td>
</tr>
</tbody>
</table>
to soft PZT, where this value is at about 50%.\(^1\)\(^2\) The deviation is larger on the tetragonal side of the MPB than on the rhombohedral side, though the extrinsic contribution to the electric-field induced strain seems larger in the rhombohedral side as was discussed above (see Fig. 7). This suggests that non-180° domain switching in rhombohedral symmetry is less effective in enhancing the total strain level.

According to literature, the piezoelectric properties of BMT-PT depend strongly on processing route.\(^1\)\(^3\)\(^-\)\(^5\)\(^1\)\(^3\)\(^-\)\(^5\) BMT-PT can be obtained with high \(d_{33}\) (225 pC/N) and large dielectric breakdown field using hot isostatic pressing.\(^1\)\(^4\) Conventional processing leads to problems with respect to high conductivity,\(^1\)\(^4\)\(^5\) and low dielectric breakdown strength (5 kV/mm).\(^1\)\(^4\) The piezoelectric coefficient (small signal \(d_{33}\) =166 pC/N) is lower when using the one-step conventional process without employing MgTiO\(_3\) as a precursor.\(^1\)\(^4\) Note that the process used here, with MgTiO\(_3\) as a precursor combined with a standard sintering technique, can yield BMT-PT with good properties, such as high \(d_{33}\) (216 pC/N) and large dielectric breakdown strength (above 8 kV/mm).

As has been demonstrated, BMT-PT is a highly promising high temperature piezoelectric; thanks to several advantages, such as high \(T_C\), high piezoelectric properties, and good thermal stability of poled domains. However, two major aspects warrant future studies. One is to improve resistivity, for example, by using dopants that have been successful in PZT materials,\(^3\)\(^3\) because improved resistivity would permit BMT-PT to be used at even higher temperatures. The other is to understand the correlation between crystal symmetry and piezoelectric properties. An interesting aspect is revealed when the small signal \(d_{33}\) value of typical BiMeO\(_3\)–PT systems is plotted as a function of the tolerance factor \(t\) at their MPB as shown in Fig. 9. The rhombohedral component phase at the MPB can either be R3c or R3m, which differs with respect to tilted or untitled oxygen octahedra. The tolerance factor \(t\) at the MPB has a lower value for the tilted R3c phase than for the untitled R3m one. At the moment, the number of data is too small to derive any meaningful correlation between \(d_{33}\) and \(t\) in R3c-based systems, but it is quite evident that the correlation between \(t\) and the small signal \(d_{33}\) depends significantly on \(t\) in R3m-based systems. BMT-PT has a MPB consisting of tetragonal \((P4mm)\) and rhombohedral \((R3c)\) phases.\(^1\)\(^3\) The R3c structure was suggested to be a reason for the low piezoelectric property, because antiphase boundaries associated with oxygen octahedral tilting act as pinning sites at domain boundaries and suppress domain wall mobility.\(^1\)\(^3\)\(^4\)\(^3\)\(^4\)\(^3\) The piezoelectric property of BMT-PT could be improved by increasing its tolerance factor at the MPB by suitable doping. The increase in \(t\) could convert the rhombohedral structure from R3c to R3m, and thus improve the piezoelectric property. In analogy, the piezoelectric property of those MPB with R3m phase may improve by decreasing the \(t\) value of the MPB to a critical one where the phase transformation of R3m to R3c takes place. Similar results can also be found in PZT.\(^3\)\(^5\) We expect that a systematic investigation on this topic will lead to a better understanding of the nature of piezoelectricity.

IV. CONCLUSIONS

The ferroelectric and piezoelectric properties of BMT-PT of compositions near the MPB were investigated as a function of temperature from room temperature to 175 °C. It was observed that the maximum and remanent polarizations \((P_{\text{max}}\) and \(P_r\)) are enhanced with temperature. The increase in the polarization values was explained in terms of the enhanced domain wall mobility due to the reduced lattice distortion at elevated temperatures. This reduced the coercive field and effectively subjected the specimen to higher normalized electric fields. Especially BMT-PT38, which lies at the tetragonal side of the MPB, was found to have a good resistance against thermal depoling above 200 °C, which suggests that tetragonal BMT-PT is promising for high temperature applications.

ACKNOWLEDGMENTS

J.C. thanks the Alexander von Humboldt foundation for financial support.


